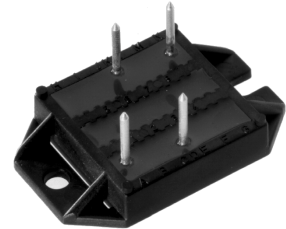
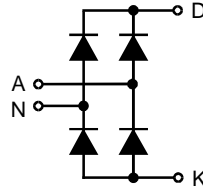


# Single Phase Rectifier Bridge

**$I_{dAV} = 68 \text{ A}$**   
 **$V_{RRM} = 800-1600 \text{ V}$**

## Preliminary data

$V_{RSM}$ V	$V_{RRM}$ V	Types
900	800	VBO 68-08NO7
1300	1200	VBO 68-12NO7
1500	1400	VBO 68-14NO7
1700	1600	VBO 68-16NO7



Symbol	Test Conditions	Maximum Ratings
$I_{dAV}$ ①	$T_C = 90^\circ\text{C}$ , module	68 A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 530 A
		$t = 8.3 \text{ ms}$ (60 Hz), sine 570 A
	$T_{VJ} = T_{VJM}$ ; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 480 A
		$t = 8.3 \text{ ms}$ (60 Hz), sine 520 A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 1400 A <sup>2</sup> s
		$t = 8.3 \text{ ms}$ (60 Hz), sine 1360 A <sup>2</sup> s
	$T_{VJ} = T_{VJM}$ ; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine 1150 A <sup>2</sup> s
		$t = 8.3 \text{ ms}$ (60 Hz), sine 1140 A <sup>2</sup> s
$T_{VJ}$		-40...+150 °C
$T_{VJM}$		150 °C
$T_{stg}$		-40...+125 °C
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	2500 V~
		3000 V~
$M_d$	Mounting torque (M4)	1.5 - 2 Nm 14 - 18 lb.in.
Weight	typ.	18 g

## Features

- Package with DCB ceramic base plate
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

## Applications

- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Advantages

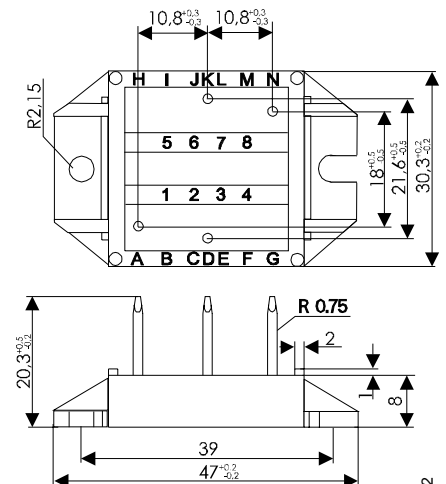
- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight

Symbol	Test Conditions	Characteristic Values
$I_R$	$V_R = V_{RRM}$ ; $V_R = V_{RRM}$	$T_{VJ} = 25^\circ\text{C}$ $\leq 0.5 \text{ mA}$
		$T_{VJ} = T_{VJM}$ $\leq 3 \text{ mA}$
$V_F$	$I_F = 80 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$	$\leq 1.5 \text{ V}$
$V_{T0}$	For power-loss calculations only	0.8 V
$r_T$		7.5 mΩ
$R_{thJC}$	per diode; DC current	1.2 K/W
	per module	0.3 K/W
$R_{thJH}$	per diode; DC current	1.5 K/W
	per module	0.38 K/W
$d_s$	Creeping distance on surface	11.2 mm
$d_A$	Creepage distance in air	9.7 mm
$a$	Max. allowable acceleration	50 m/s <sup>2</sup>

Data according to IEC 60747 refer to a single diode unless otherwise stated  
 ① for resistive load at bridge output.

IXYS reserves the right to change limits, test conditions and dimensions.

## Dimensions in mm (1 mm = 0.0394")



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